

Model SM08010-34HS

800-1000 MHz 3 Watt Linear Power Amplifier FOR GSM APPLICATIONS

Stealth Microwave's SM08010-34HS is an 800-1000 MHz solid state GaAs amplifier designed for multiple wireless markets. 200 MHz of With instantaneous bandwidth, the amplifier can be used in most GSM and Cellular applications. The P1dB is +34 dBm, the IP3 is typically +47 dBm, the linear gain is 36 dBm, and the gain flatness across the band is \pm 0.5 dB. The amplifier operates off a single DC supply of +12 V, with +10 V available as an option. The unit uses the latest surface mount technologies to provide numerous features, while maintaining a very small size.

Features

- Mis-Match Protected
- Single Power Supply
- Over Voltage Protection
- Thermal Protection with Auto Reset

Options

- Logic On/Off Control
- Integral Heatsink
- Single DC Supply of +10 V

Configurations

- Module
- Bench-Top Lab Unit
- 19" Rack Mount



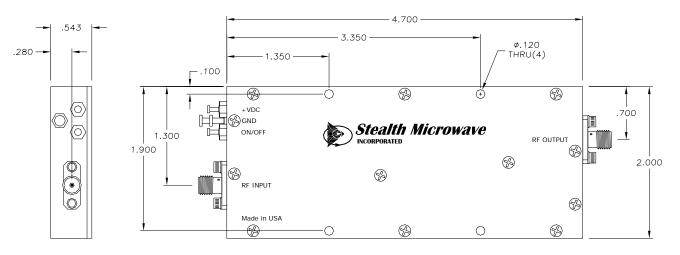
Parameter	Specification
Frequency Range	800 - 1000 MHz
Pout (P1dB)	+ 34 dBm
Third Order Intercept Point	+ 47 dBm (typ.)
Linear Gain	$36 \text{ dB} \pm 1.0 \text{ dB}$
Gain Flatness over Full Band	± .5 dB
Input/Output Return Loss	-16 dB / -16 dB
DC Input Voltage	+12 Volts (+10 Volts available)
DC Input Current	1.2 Amperes (typ.)
Mechanical Dimensions	4.7 x 2.0 x .54 inches
RF Connectors	SMA Female
Operating Temperature (Baseplate)	0°C to +55°C
Operating Humidity	95% Non-condensing
Operating Altitude	Up to 10,000 feet above Sea Level



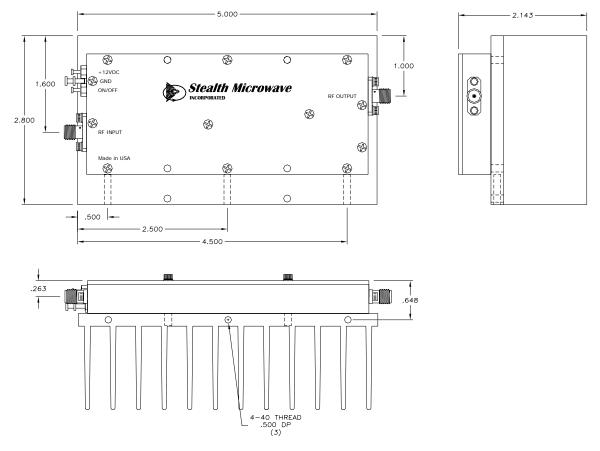
Model SM08010-34HS

800-1000 MHz 3 Watt Linear Power Amplifier FOR GSM APPLICATIONS





HEATSINK OPTION





800-1000 MHz 3 Watt Linear Power Amplifier FOR GSM APPLICATIONS

Pin	Description	Values
RF Input	Input Connector (SMA Female)	0 dBm max
RF Output	Output Connector (SMA Female)	+ 34 dBm @ P1dB
GND	Ground Turret	
+ VDC	DC Input Voltage	+ 12 Volts
On/Off	TTL Logic On/Off	0 Volts = Off, +5 Volts = On

Specifications subject to change without notice.